

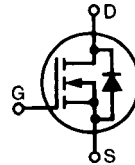
# MegaMOS™ FET

Obsolete:  
IXTM20N60

**IXTH 20N60**  
~~IXTM 20N60~~

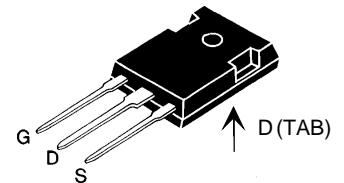
$V_{DSS} = 600\text{ V}$   
 $I_{D25} = 20\text{ A}$   
 $R_{DS(on)} = 0.35\ \Omega$

## N-Channel Enhancement Mode



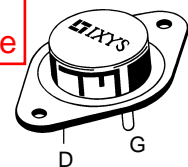
| Symbol  | Test Conditions   | Maximum Ratings             |                  |
|---|---|-----------------------------|------------------|
| $V_{DSS}$   | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                               | 600                         | V                |
| $V_{DGR}$   | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1\text{ M}\Omega$ | 600                         | V                |
| $V_{GS}$  | Continuous  | $\pm 20$                    | V                |
| $V_{GSM}$   | Transient   | $\pm 30$                    | V                |
| $I_{D25}$   | $T_C = 25^\circ\text{C}$  | 15N60                       | 15 A             |
|   |   | 20N60                       | 20 A             |
| $I_{DM}$  | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$                    | 15N60                       | 60 A             |
|   |   | 20N60                       | 80 A             |
| $P_D$   | $T_C = 25^\circ\text{C}$  | 300                         | W                |
| $T_J$   |   | -55 ... +150                | $^\circ\text{C}$ |
| $T_{JM}$  |   | 150                         | $^\circ\text{C}$ |
| $T_{stg}$   |   | -55 ... +150                | $^\circ\text{C}$ |
| $M_d$   | Mounting torque   | 1.13/10                     | Nm/lb.in.        |
| <b>Weight</b>   |   | TO-204 = 18 g, TO-247 = 6 g |                  |
| Maximum lead temperature for soldering<br>1.6 mm (0.062 in.) from case for 10 s |   | 300                         | $^\circ\text{C}$ |

TO-247 AD (IXTH)



TO-204 AE (IXTM)

Package  
unavailable



G = Gate, D = Drain,  
S = Source, TAB = Drain

### Features

- International standard packages
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Low package inductance (< 5 nH)
  - easy to drive and to protect
- Fast switching times

### Applications

- Switch-mode and resonant-mode power supplies
- Motor control
- Uninterruptible Power Supplies (UPS)
- DC choppers

### Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- Space savings
- High power density

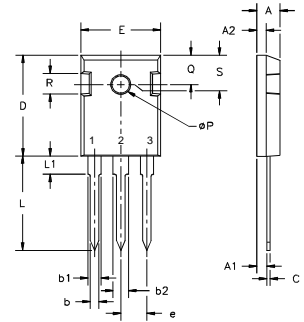
| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                     |
|--------------|---|---|------|---------------------|
|              |   | min.  | typ. | max.                |
| $V_{DSS}$    | $V_{GS} = 0\text{ V}$ , $I_D = 250\ \mu\text{A}$  | 600   |      | V                   |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\ \mu\text{A}$  | 2   |      | 4.5 V               |
| $I_{GSS}$    | $V_{GS} = \pm 20\text{ V}_{DC}$ , $V_{DS} = 0$  |   |      | $\pm 100\text{ nA}$ |
| $I_{DSS}$    | $V_{DS} = 0.8 \cdot V_{DSS}$<br>$V_{GS} = 0\text{ V}$   | $T_J = 25^\circ\text{C}$  |      | 200 $\mu\text{A}$   |
|              |   | $T_J = 125^\circ\text{C}$   |      | 1 mA                |
| $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$ , $I_D = 0.5 I_{D25}$<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |   |      | 0.35 $\Omega$       |

| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |      |    |
|--------------|---|---|------|------|----|
|              |   | min.  | typ. | max. |    |
| $g_{fs}$     | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$ , pulse test  | 11  | 18   | S    |    |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$   |   | 4500 | pF   |    |
| $C_{oss}$    |   |   | 420  | pF   |    |
| $C_{rss}$    |   |   | 140  | pF   |    |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 I_{D25}$<br>$R_G = 2\ \Omega$ , (External) |   | 20   | 40   | ns |
| $t_r$        |   |   | 43   | 60   | ns |
| $t_{d(off)}$ |   |   | 70   | 90   | ns |
| $t_f$        |   |   | 40   | 60   | ns |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 I_{D25}$                                   |   | 150  | 170  | nC |
| $Q_{gs}$     |   |   | 29   | 40   | nC |
| $Q_{gd}$     |   |   | 60   | 85   | nC |
| $R_{thJC}$   |   |   | 0.42 | K/W  |    |
| $R_{thCK}$   |   | 0.25  |      | K/W  |    |

### Source-Drain Diode

| Symbol   | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |      |    |
|----------|---|---|------|------|----|
|          |   | min.  | typ. | max. |    |
| $I_S$    | $V_{GS} = 0\text{ V}$   |   |      | 20   | A  |
| $I_{SM}$ | Repetitive;   |   |      | 80   | A  |
| $V_{SD}$ | $I_F = I_S, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |   |      | 1.5  | V  |
| $t_{rr}$ | $I_F = I_S, -di/dt = 100\text{ A}/\mu\text{s}, V_R = 100\text{ V}$                                    |   | 600  |      | ns |

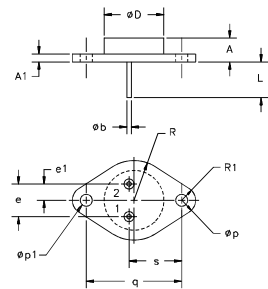
### TO-247 AD (IXTH) Outline



Terminals: 1 - Gate 2 - Drain  
3 - Source Tab - Drain

| Dim.           | Millimeter |       | Inches |       |
|----------------|------------|-------|--------|-------|
|                | Min.       | Max.  | Min.   | Max.  |
| A              | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub> | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub> | 2.2        | 2.6   | .059   | .098  |
| b              | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub> | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub> | 2.87       | 3.12  | .113   | .123  |
| C              | .4         | .8    | .016   | .031  |
| D              | 20.80      | 21.46 | .819   | .845  |
| E              | 15.75      | 16.26 | .610   | .640  |
| e              | 5.20       | 5.72  | 0.205  | 0.225 |
| L              | 19.81      | 20.32 | .780   | .800  |
| L1             |            | 4.50  |        | .177  |
| ØP             | 3.55       | 3.65  | .140   | .144  |
| Q              | 5.89       | 6.40  | 0.232  | 0.252 |
| R              | 4.32       | 5.49  | .170   | .216  |
| S              | 6.15       | BSC   | 242    | BSC   |

### TO-204AE (IXTM) Outline



Pins 1 - Gate 2 - Source  
Case - Drain

| Dim.            | Millimeter |           | Inches |           |
|-----------------|------------|-----------|--------|-----------|
|                 | Min.       | Max.      | Min.   | Max.      |
| A               | 6.4        | 11.4      | .250   | .450      |
| A <sub>1</sub>  | 1.53       | 3.42      | .060   | .135      |
| Øb              | 1.45       | 1.60      | .057   | .063      |
| ØD              |            | 22.22     |        | .875      |
| e               | 10.67      | 11.17     | .420   | .440      |
| e <sub>1</sub>  | 5.21       | 5.71      | .205   | .225      |
| L               | 11.18      | 12.19     | .440   | .480      |
| Øp              | 3.84       | 4.19      | .151   | .165      |
| Øp <sub>1</sub> | 3.84       | 4.19      | .151   | .165      |
| q               |            | 30.15 BSC |        | 1.187 BSC |
| R               | 12.58      | 13.33     | .495   | .525      |
| R <sub>1</sub>  | 3.33       | 4.77      | .131   | .188      |
| s               | 16.64      | 17.14     | .655   | .675      |

Fig. 1 Output Characteristics

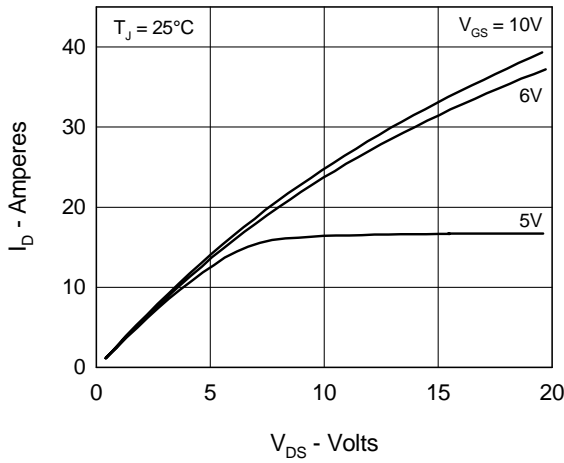


Fig. 2 Input Admittance

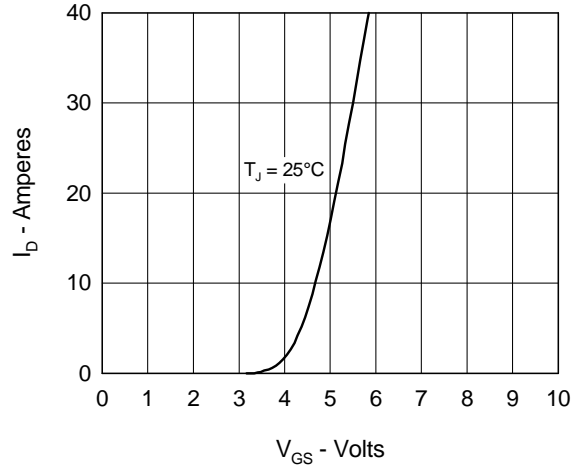


Fig. 3  $R_{DS(on)}$  vs. Drain Current

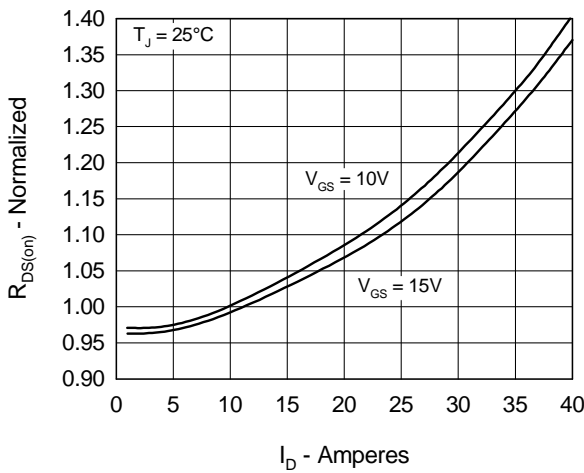


Fig. 4 Temperature Dependence of Drain to Source Resistance

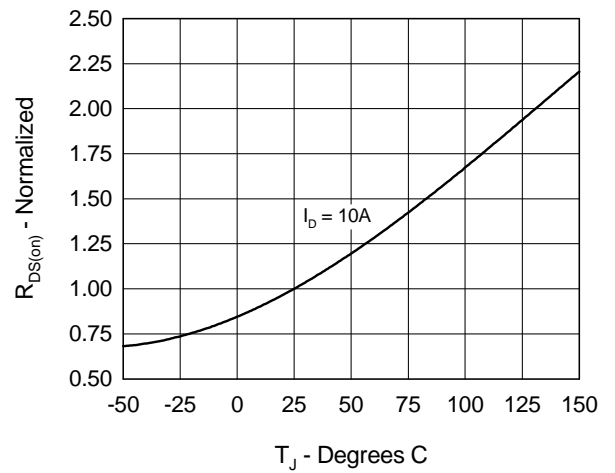


Fig. 5 Drain Current vs. Case Temperature

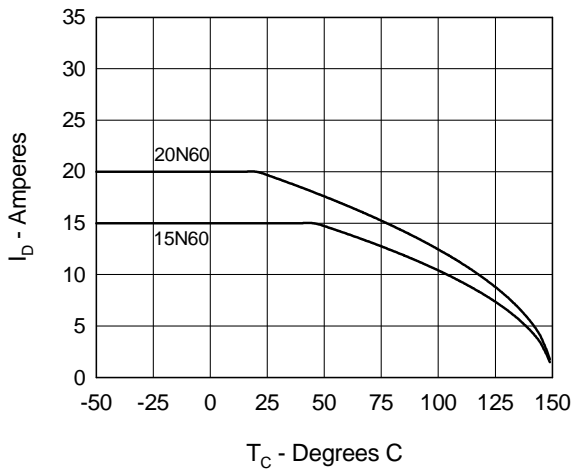
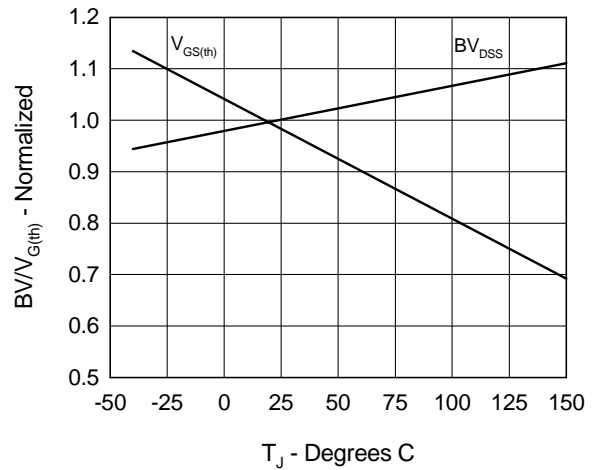
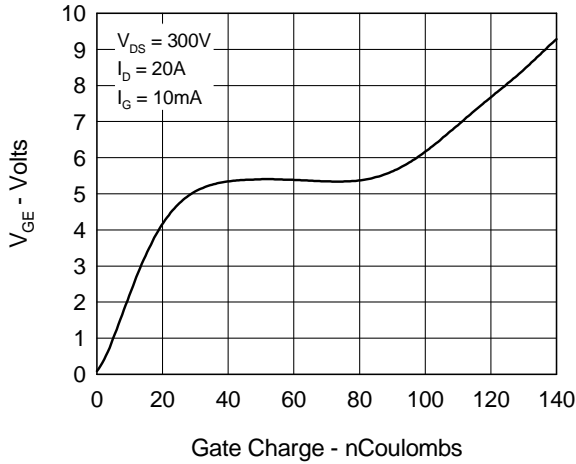


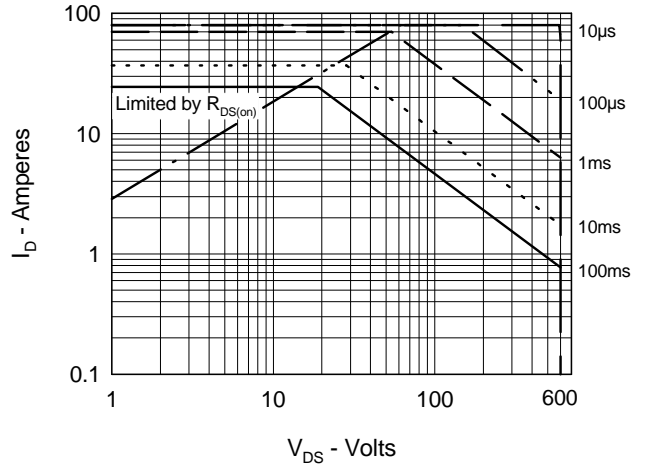
Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage



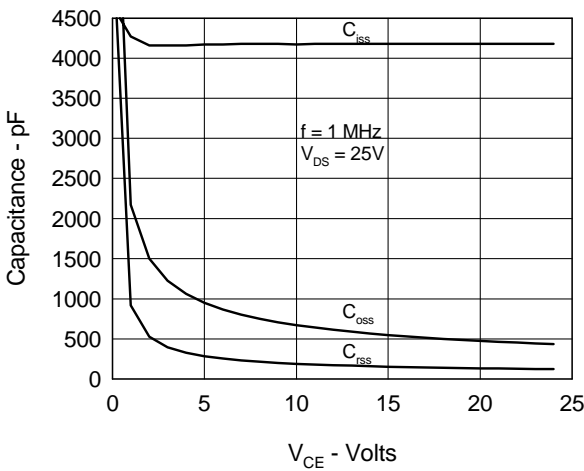
**Fig.7 Gate Charge Characteristic Curve**



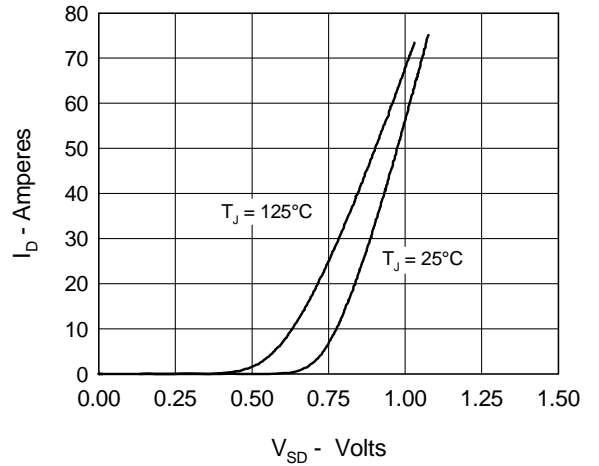
**Fig.8 Forward Bias Safe Operating Area**



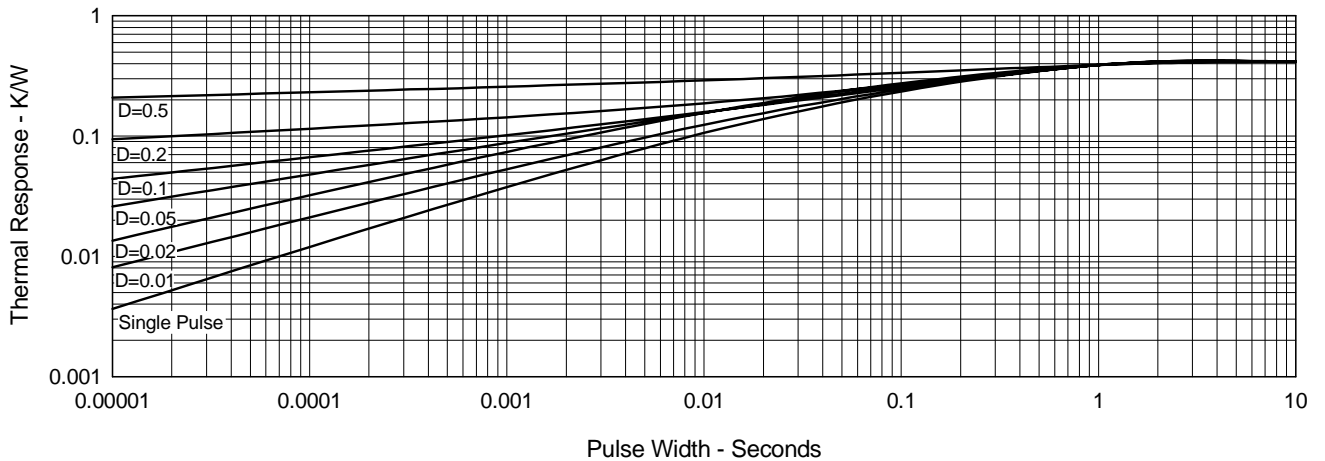
**Fig.9 Capacitance Curves**



**Fig.10 Source Current vs. Source to Drain Voltage**



**Fig.11 Transient Thermal Impedance**





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